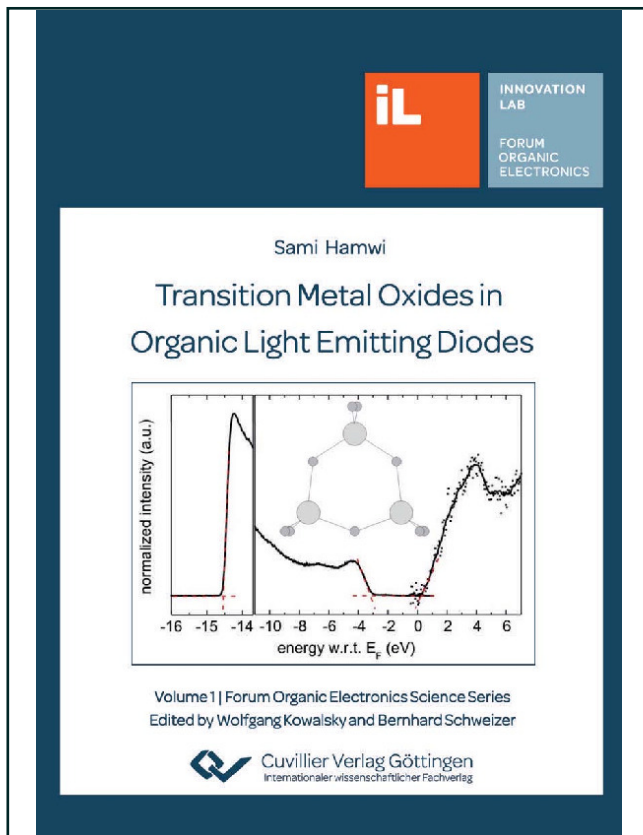




Sami Hamwi (Autor)

Transition Metal Oxides in Organic Light Emitting Diodes



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Contents

List of Abbreviations	ix
1 Introduction	1
1.1 Organic Light Emitting Diodes	1
1.2 Transition Metal Oxides	3
1.3 Goals and Outline	3
2 Fundamentals of Organic Devices	6
2.1 Small Molecules with Conjugated π -Systems	6
2.2 Organic Semiconductors	8
2.2.1 Charge Transport	8
2.2.2 Energetics of Interfaces and Charge Injection	11
2.2.3 Doping Approach	14
2.2.4 Formation and Transfer of Excitons	16
2.3 Functional Principle of Organic Light Emitting Diodes	20
2.3.1 Internal Quantum Efficiency	20
2.3.2 External Quantum Efficiency	22
3 Preparation and Characterization	24
3.1 Deposition Technology	24
3.1.1 Organic Molecular Beam Deposition	24
3.1.2 Atomic Layer Deposition	25
3.2 Device Preparation	27
3.3 Analytical Methods	29
3.3.1 Ultraviolet and Inverse Photoelectron Spectroscopy	29
3.3.2 Kelvin Probe Technique	36
3.3.3 Electro-Optical Characterization	38
4 Fundamental Properties of Transition Metal Oxides	43
4.1 Electronic Structure of MoO_3 and WO_3	43
4.2 Insertion of Neat TMO Layers into OLEDs	48

4.2.1	Hole Injection	49
4.2.2	Electron Blocking	53
4.2.3	Luminescence Quenching	54
4.3	Conclusion	58
5	Electrochemical Doping of Organic Semiconductors by MoO₃ and Cs₂CO₃	60
5.1	P-Type Doping of CBP by MoO ₃	60
5.1.1	Analysis of P-Type Doping via UPS and KP	61
5.1.2	Impact of P-Type Doping on the Properties of CBP	65
5.2	N-Type Doping of CBP by Cs ₂ CO ₃	72
5.2.1	Analysis of N-Type Doping by UPS, IPES and KP	72
5.2.2	Impact of N-Type Doping on the Properties of CBP	77
5.3	Determination of Excess Charge Carrier Densities in Doped Organic Semiconductors	79
5.3.1	Thickness-Dependent Work Function Characteristics of Doped Organic Semiconductors on ITO	81
5.3.2	Capacitance-Voltage Measurements on Metal-Insulator-Semiconductor Structures	85
5.4	Doping Efficiencies of MoO ₃ and Cs ₂ CO ₃ in Organic Semiconductors	93
5.5	Conclusion	97
6	Stacked OLEDs with Charge Generation Layers	100
6.1	Mechanism of Charge Generation in p-n Homojunctions	100
6.2	Mechanism of Charge Generation in TMO based Interconnecting Units	107
6.3	Conclusion	117
7	P-I-N Homojunction Device as Violet LED and Visible Blind Photodiode in One	119
7.1	Operation as Visible Blind Photodiode	119
7.2	Operation as Violet Light Emitting Diode	124
7.3	Conclusion	127
8	Summary	128
A	Molecular Structures	131
	List of Publications	134
	Bibliography	136